

# Spin Noise of Electrons and Holes in Self-Assembled Quantum Dots

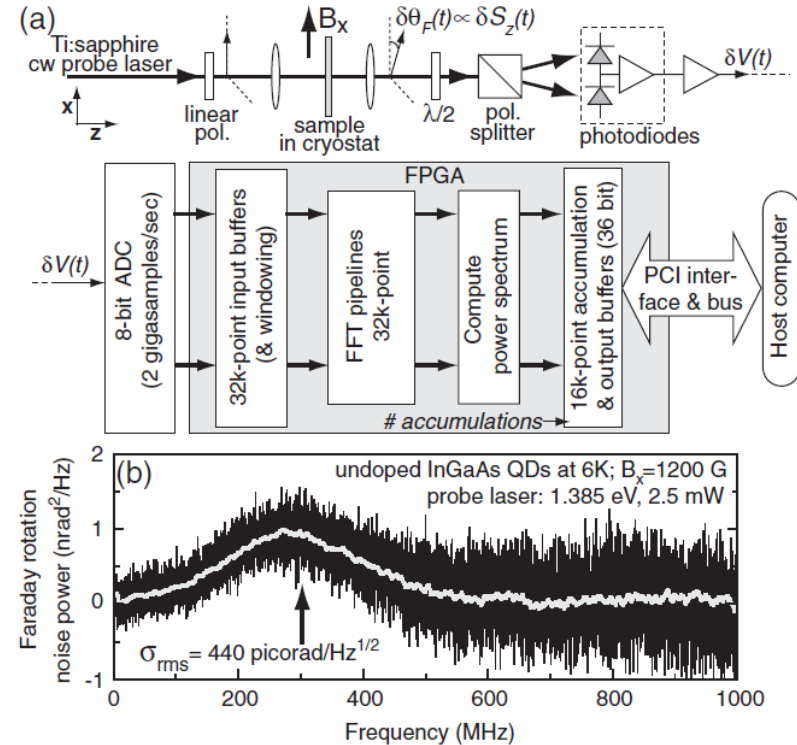
S. A. Crooker<sup>1</sup>, J. Brandt<sup>2</sup>, C. Sandfort<sup>2</sup>, A. Greilich<sup>2</sup>, D. R. Yakovlev<sup>2</sup>, D. Reuter<sup>3</sup>, A. D. Wieck<sup>3</sup>, and M. Bayer<sup>2</sup>

<sup>1</sup>National High Magnetic Field Laboratory, Los Alamos National Lab, USA

<sup>2</sup>Technische Universität Dortmund, Dortmund, Germany; <sup>3</sup>Ruhr-Universität Bochum, Bochum, Germany

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- The dynamic properties of electron and hole spins in semiconductor quantum dots (QDs) are actively investigated for potential applications in spintronics and quantum computing. Optical pump-probe studies have proven invaluable in this regard, directly revealing the g-factors and coherence decays of spins in QDs. In principle, however, these important properties are *also* accessible via alternative measurement approaches based on “spin noise”, in which the intrinsic spin fluctuation spectra of the spins – if measurable – also reveal this dynamical information, in accord with the Fluctuation-Dissipation Theorem. In general, spin noise signals scale favorably as the number of measured spins  $N$  decreases (falling only as  $\sqrt{N}$ ), suggesting their use as viable probes of few-spin systems.



- We measure spin noise in ensembles of InGaAs QDs at low temperatures. We employ a spin noise spectrometer based on a sensitive optical Faraday rotation magnetometer that is coupled to a digitizer and field-programmable gate array, to measure and average noise spectra from 0–1 GHz continuously in real time with sub-nanoradian/root-Hz sensitivity (see Figure). Both electron and hole spin fluctuations generate distinct noise peaks, whose shift and broadening with magnetic field directly reveal their g factors and dephasing rates within ensemble. Large, energy-dependent anisotropies of the in-plane hole g-factor are clearly exposed, reflecting systematic variations in the average QD confinement potential.